TRIPLE DIFFUSED PLANER TYPE HIGH VOLTAGE, HIGH SPEED SWITCHING

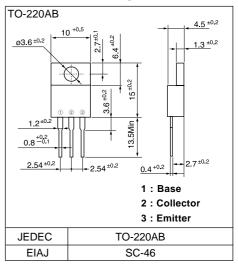
■ Features

- High voltage, High speed switching
- High reliability

■ Applications

- Switching regulators
- Ultrasonic generators
- High frequency inverters
- General purpose power amplifiers

■ Outline Drawings



■ Maximum ratings and characteristics

Absolute maximum ratings (Tc=25°C unless otherwise specified)

Item	Symbol	Ratings	Unit
Collector-Base voltage	Vсво	450	V
Collector-Emitter voltage	VCEO	400	V
Collector-Emitter voltage	VCEO(SUS)	400	V
Emitter-Base voltage	VEBO	7	V
Collector current	lc	5	A
Base current	lв	1.5	Α
Collector power disspation	Pc	40	W
Operating junction temperature	T _j	+150	℃
Storage temperature	Tstg	-45 to +150	℃

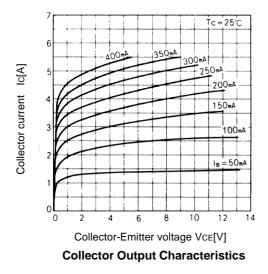
● Electrical characteristics (Tc =25°C unless otherwise specified)

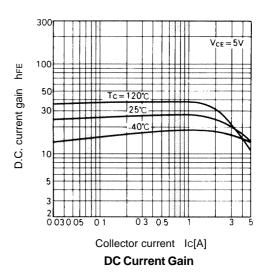
Item	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Collector-Base voltage	Vсво	ICBO = 0.1mA	400			V
Collector-Emitter voltage	VCEO	ICEO = 10mA	400			V
Collector-Emitter voltage	VCEO(SUS)	Ic = 1A	400	-		V
Emitter-Base voltage	VEBO	IEBO = 0.1mA	7	-		V
Collector-Base leakage current	Ісво	VcBo = 400V		-	0.1	mA
Emitter-Base leakage current	I EBO	VEBO = 7V		-	0.1	mA
D.C. current gain	hFE	IC = 2A, VCE = 5V	15			
Collector-Emitter saturation voltage	VCE(Sat)	IC = 2A, IB = 0.4A			0.8	V
Base-Emitter saturation voltage	VBE(Sat)				1.5	V
*1	ton	Ic = 3A, IB1 = 0.3A			1.5	μs
Switching time	t stg	IB2 = -0.3A, $RL = 20$ ohm			4.0	μs
	tf	Pw = 20µs Duty=<2%			1.3	μs

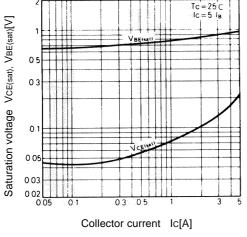
Thermal characteristics

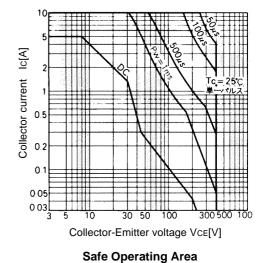
Item	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Thermal resistance	Rth(j-c)	Junction to case			3.0	°C/W

Characteristics

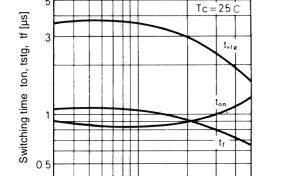




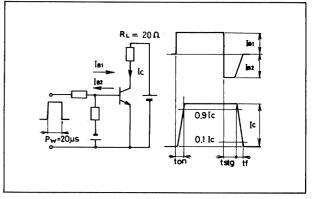




Base and Collector Saturation Voltage



* Switching Time Test Circuir



Switching Time

Collector current Ic[A]

3

03

0.5